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Texas Instruments
THS3001CD

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Datasheet of THS3001CD - IC OPAMP CFA 1.75GHZ 8SOIC

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#### 420-MHz HIGH-SPEED CURRENT-FEEDBACK AMPLIFIER

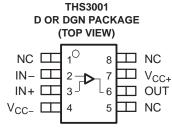
Check for Samples: THS3001

#### **FEATURES**

- · High Speed:
  - 420-MHz Bandwidth (G = 1, -3 dB)
  - 6500-V/µs Slew Rate
  - 40-ns Settling Time (0.1%)
- High Output Drive: I<sub>O</sub> = 100 mA
- Excellent Video Performance
  - 115-MHz Bandwidth (0.1 dB, G = 2)
  - 0.01% Differential Gain
  - 0.02° Differential Phase
- Low 3-mV (max) Input Offset Voltage
- Very Low Distortion:
  - THD = -96 dBc at f = 1 MHz
  - THD = -80 dBc at f = 10 MHz
- Wide Range of Power Supplies:
  - $V_{CC} = \pm 4.5 \text{ V to } \pm 16 \text{ V}$
- Evaluation Module Available

#### **APPLICATIONS**

- Communication
- Imaging
- High-Quality Video



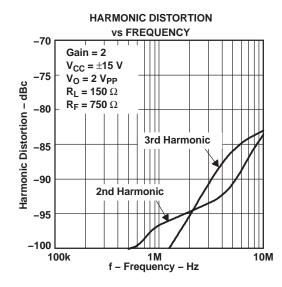
NC - No internal connection

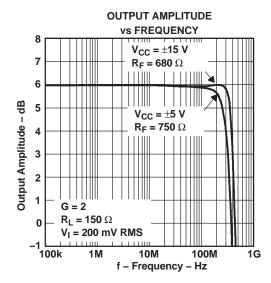
#### **RELATED DEVICES**

THS4011 /2	290-MHz VFB High-Speed Amplifier
THS6012	500-mA CFB Hlgh-Speed Amplifier
THS6022	250-mA CFB High-Speed Amplifier

#### **DESCRIPTION**

The THS3001 is a high-speed current-feedback operational amplifier, ideal for communication, imaging, and high-quality video applications. This device offers a very fast 6500-V/µs slew rate, a 420-MHz bandwidth, and 40-ns settling time for large-signal applications requiring excellent transient response. In addition, the THS3001 operates with a very low distortion of –96 dBc, making it well suited for applications such as wireless communication basestations or ultrafast ADC or DAC buffers.





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **AVAILABLE OPTIONS**(1)

		PACKAGED DEVICE		TRANSPORT MEDIA	EVALUATION
T <sub>A</sub>	SOIC (D)	MSOP (DGN)	MSOP SYMBOL	TRANSPORT MEDIA, QUANTITY	MODULE
	THS3001CD	THS3001CDGN	ADP	Rails, 75	THS3001EVM
0°C to 70°C	THS3001CDR	THS3001CDGNR	ADP	Tape and Reel, 2500	
0 0 10 70 0		THS3001HVCDGN	BNK	Rails, 75	
		THS3001HVCDGNR	DINK	Tape and Reel, 2500	
	THS3001ID	THS3001IDGN	ADQ	Rails, 75	
-40°C to 85°C	THS3001IDR THS3001IDGNR		ADQ	Tape and Reel, 2500	
-40 C to 65 C		THS3001HVIDGN	BNJ	Rails, 75	
		THS3001HVIDGNR	DINJ	Tape and Reel, 2500	

<sup>(1)</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

#### ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			THS3001	THS3001HV	UNITS	
V <sub>SS</sub>	Supply voltage, V <sub>CC+</sub> to V <sub>CC-</sub>	33	37	V		
$V_{I}$	Input voltage		±V <sub>CC</sub>	±V <sub>CC</sub>	٧	
Io	Output current	Output current				
$V_{\text{ID}}$	Differential input voltage	±6	±6	٧		
	Continuous total power dissipation	Continuous total power dissipation				
$T_J$	Maximum junction temperature (2)		150	150	ů	
TJ	Maximum junction temperature, continuous	operation, long term reliability <sup>(3)</sup>	125	125	°C	
т	Operating free air temperature	THS3001C, THS3001HVC	0 to 70	0 to 70	°C	
T <sub>A</sub>	Operating free-air temperature	THS3001I, THS3001HVI	-40 to 85	-40 to 85	°C	
T <sub>stg</sub>	Storage temperature		-65 to 125	-65 to 125	°C	

<sup>(1)</sup> Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) The absolute maximum temperature under any condition is limited by the constraints of the silicon process.

#### **DISSIPATION RATING TABLE**

PACKAGE	θ <sub>JC</sub>	θ <sub>JA</sub> <sup>(1)</sup>	POWER R	RATING (2)
PACKAGE	(°C/W)	(°C/W)	T <sub>A</sub> ≤ 25°C	T <sub>A</sub> = 85°C
D (8)	38.3	97.5	1.02 W	410 mW
DGN (8)	4.7	58.4	1.71 W	685 mW

(1) This data was taken using the JEDEC standard High-K test PCB.

<sup>(3)</sup> The maximum junction temperature for continuous operation is limited by package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device.

<sup>(2)</sup> Power rating is determined with a junction temperature of 125°C. This is the point where distortion starts to substantially increase. Thermal management of the final PCB should strive to keep the junction temperature at or below 125°C for best performance and long term reliability.



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### RECOMMENDED OPERATING CONDITIONS

				MIN	NOM	MAX	UNIT
	Split supply THS3001C,	±4.5		±16			
	Cumply valtage V and V	Single supply	THS3001I	9		32	V
V <sub>SS</sub>	Supply voltage, $V_{CC+}$ and $V_{CC-}$	Split supply	THS3001HVC,	±4.5		±18.5	
		Single supply THS3001HVI		9		37	
T <sub>A</sub>	Operating free air temperature	THS3001C, THS30	001HVC	0		70	°C
	Operating free-air temperature	THS3001I, THS30	S3001I, THS3001HVI			85	

#### **ELECTRICAL CHARACTERISTICS**

At  $T_A = 25$ °C,  $R_L = 150 \Omega$ ,  $R_F = 1 k\Omega$  (unless otherwise noted)

	PARAMETER		TEST CONI	DITIONS (1)	MIN	TYP	MAX	UNIT
			Split supply	THS3001C THS3001I	±4.5		±16.5	
M	Daa. aa.b. aa aast			THS3001HVx	±4.5		±18.5	,,
V <sub>CC</sub>	Power supply operati	ing range	Single supply	THS3001C THS3001I	9		33	V
				THS3001HVx	9		37	
				T <sub>A</sub> = 25°C		5.5	7.5	
			$V_{CC} = \pm 5 \text{ V}$	T <sub>A</sub> = full range			8.5	
	0		V .45.V	T <sub>A</sub> = 25°C		6.6	9	A
I <sub>CC</sub>	Quiescent current		$V_{CC} = \pm 15 \text{ V}$	T <sub>A</sub> = full range			10	mA
			$V_{CC} = \pm 18.5 \text{ V},$	T <sub>A</sub> = 25°C		6.9	9.5	
			THS3001HV	T <sub>A</sub> = full range			10.5	
			V .5.V	$R_L = 150 \Omega$	±2.9	±3.2		
Vo			$V_{CC} = \pm 5 \text{ V}$	$R_L = 1 k\Omega$	±3	±3.3		.,
	Output voltage swing		.,	$R_L = 150 \Omega$	±12.1	±12.8		V
			$V_{CC} = \pm 15 \text{ V}$	$R_L = 1 k\Omega$	±12.8	±13.1		
	Output current <sup>(2)</sup>		$V_{CC} = \pm 5 \text{ V},$	R <sub>L</sub> = 20 Ω		100		^
I <sub>O</sub>			$V_{CC} = \pm 15 \text{ V},$	R <sub>L</sub> = 75 Ω	85	120		mA
	Lead office to all the con-	$T_A = 25^{\circ}C$		T <sub>A</sub> = 25°C		1	3	
$V_{IO}$	Input offset voltage		$V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$	T <sub>A</sub> = full range			4	mV
	Input offset voltage d	rift	$V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$			5		μV/°C
		Desitive (INL)		T <sub>A</sub> = 25°C		2	10	
	To a difference of	Positive (IN+)	577 4577	T <sub>A</sub> = full range			15	
I <sub>IB</sub>	Input bias current	Nametica (INI.)	$V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$	T <sub>A</sub> = 25°C		1	10	μA
		Negative (IN-)		T <sub>A</sub> = full range			15	
	0		$V_{CC} = \pm 5 \text{ V}$		±3	±3.2		V
$V_{ICR}$	Common-mode input	voltage range	V <sub>CC</sub> = ±15 V		±12.9	±13.2		V
	0		$V_{CC} = \pm 5 \text{ V}, V_{O} = \pm 2.5$	V, R <sub>L</sub> = 1 kΩ	1	1.3		140
Open loop transresistance			$V_{CC} = \pm 15 \text{ V}, V_{O} = \pm 7.5$	5 V, R <sub>L</sub> = 1 kΩ		2.4		МΩ
CMDD	Common made	tion ratio	$V_{CC} = \pm 5 \text{ V}, V_{CM} = \pm 2.5$	5 V	62	70		٩D
CMRR	Common-mode rejec	เเบท เสแบ	$V_{CC} = \pm 15 \text{ V}, V_{CM} = \pm 1$	0 V	65	73		dB
			V .5.V	T <sub>A</sub> = 25°C	65	76		٩D
DCDD	Dower over by anti-of	an ratio	$V_{CC} = \pm 5 \text{ V}$	T <sub>A</sub> = full range	63			dB
PSRR	Power supply rejection ratio		V .45 V	T <sub>A</sub> = 25°C	69	76		-ID
			$V_{CC} = \pm 15 \text{ V}$	T <sub>A</sub> = full range	67			dB

<sup>(1)</sup> Full range = 0°C to 70°C for the THS3001C and -40°C to 85°C for the THS3001I.

<sup>(2)</sup> Observe power dissipation ratings to keep the junction temperature below absolute maximum when the output is heavily loaded or shorted. See Absolute Maximum Ratings table.



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#### **ELECTRICAL CHARACTERISTICS (continued)**

At  $T_A$  = 25°C,  $R_L$  = 150  $\Omega$  ,  $R_F$  = 1  $k\Omega$  (unless otherwise noted)

	PARAMETER		TEST CONDITIONS (1)	MIN	TYP	MAX	UNIT
R <sub>I</sub>	lanut registeres	Positive (IN+)			1.5		ΜΩ
	Input resistance	Negative (IN-)			15		Ω
Cı	Differential input cap	acitance			7.5		pF
Ro	Output resistance		Open loop at 5 MHz		10		Ω
V <sub>n</sub>	Input voltage noise		V <sub>CC</sub> = ±5 V or ±15 V, f = 10 kHz, G = 2		1.6		nV/√ <del>Hz</del>
In	logut ourrent naige	Positive (IN+)	V <sub>CC</sub> = ±5 V or ±15 V, f = 10 kHz, G = 2		13		π Λ /s/II=
	Input current noise	Input current noise Negative (IN-) $V_{CC} = \pm 5 \text{ V or } \pm 7$			16		pA/√Hz

#### **OPERATING CHARACTERISTICS**

 $T_A = 25^{\circ}C$ ,  $R_L = 150 \Omega$ ,  $R_F = 1 k\Omega$  (unless otherwise noted)

	PARAMETER	TEST CONDITIO	NS	MIN TYP	MAX	UNIT
		V <sub>CC</sub> = ±5 V,	G = -5	1700		
CD.	Slew rate <sup>(1)</sup>	$V_{O(PP)} = 4 \text{ V}$	G = 5	1300		\//
SR	Siew rate (1)	V <sub>CC</sub> = ±15 V,	G = -5	6500		V/µs
		$V_{O(PP)} = 20 \text{ V}$	G = 5	6300		
	Settling time to 0.1%	V <sub>CC</sub> = ±15 V, 0 V to 10 V Step	Gain = −1,	40		
t <sub>s</sub>	Settling time to 0.1%	V <sub>CC</sub> = ±5 V, 0 V to 2 V Step,	Gain = −1,	25		ns
THD	Total harmonic distortion	$V_{CC} = \pm 15 \text{ V},$ $f_{c} = 10 \text{ MHz},$	$V_{O(PP)} = 2 V,$ G = 2	-80		dBc
	Differential gain arror	G = 2, 40 IRE modulation,	$V_{CC} = \pm 5 \text{ V}$	0.015%		
	Differential gain error	±100 IRE Ramp, NTSC and PAL	$V_{CC} = \pm 15 \text{ V}$	0.01%		
	Differential phase error	G = 2, 40 IRE modulation,	$V_{CC} = \pm 5 \text{ V}$	0.01°		
	Differential phase entit	±100 IRE Ramp, NTSC and PAL	$V_{CC} = \pm 15 \text{ V}$	0.02°		
		$G = 1$ , $R_F = 1 k\Omega$	$V_{CC} = \pm 5 \text{ V}$	330		MHz
		G = 1, NF = 1 KΩ	$V_{CC}$ = ±15 V	420		MHz
	Small signal bandwidth (-3 dB)	$G = 2$ , $R_F = 750 \Omega$ ,	$V_{CC} = \pm 5 \text{ V}$	300		
BW		$G = 2$ , $R_F = 680 \Omega$ ,	V <sub>CC</sub> = ±15 V	385		MHz
		$G = 5, R_F = 560 \Omega,$	V <sub>CC</sub> = ±15 V	350		
	Bandwidth for 0.1 dB flatness	$G = 2$ , $R_F = 750 \Omega$ ,	$V_{CC} = \pm 5 \text{ V}$	85		MHz
	Dandwidth for 0.1 db flattless	$G = 2$ , $R_F = 680 \Omega$ ,	$V_{CC} = \pm 15 \text{ V}$	115		IVIITZ
		$V_{CC} = \pm 5 \text{ V}, V_{O(PP)} = 4 \text{ V},$	G = -5	65		
F. II		$R_L = 500 \Omega$	G = 5	62		MHz
	Full power bandwidth <sup>(2)</sup>	$V_{CC} = \pm 15 \text{ V}, V_{O(PP)} = 20 \text{ V},$	G = -5	32		IVIITZ
		$R_L = 500 \Omega$	G = 5	31		

Slew rate is measured from an output level range of 25% to 75%. Full power bandwidth is defined as the frequency at which the output has 3% THD.

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#### PARAMETER MEASUREMENT INFORMATION

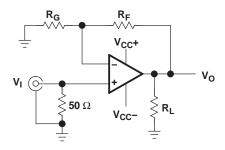


Figure 1. Test Circuit, Gain =  $1 + (R_F/R_G)$ 

#### TYPICAL CHARACTERISTICS

### **Table of Graphs**

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l <sub>n</sub>	Current noise	vs Frequency	11
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	Small signal pulse response		37, 38
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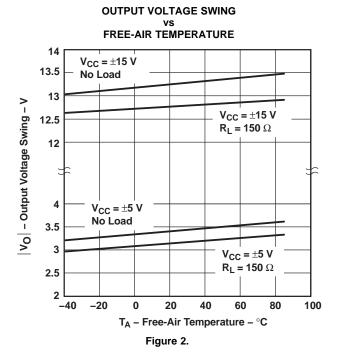


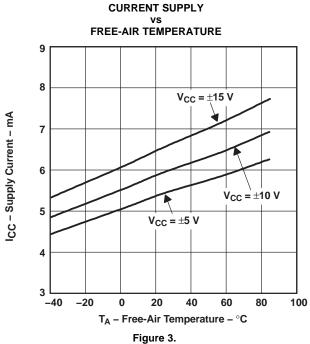
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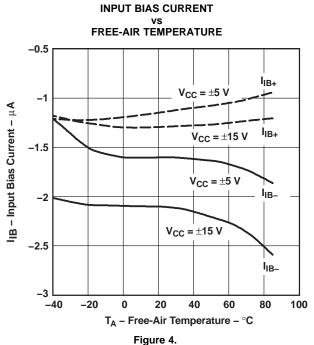
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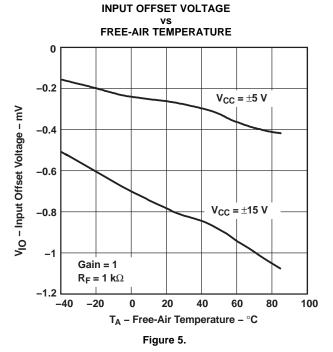
#### TYPICAL CHARACTERISTICS

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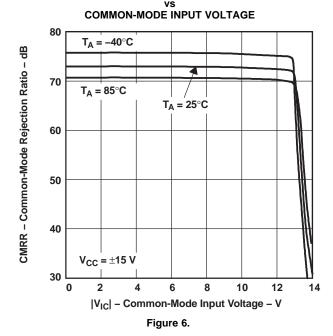


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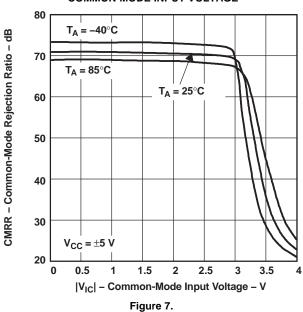
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#### **TYPICAL CHARACTERISTICS (continued)**

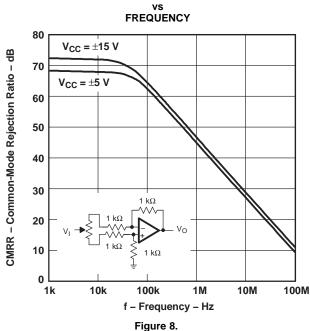
# COMMON-MODE REJECTION RATIO vs



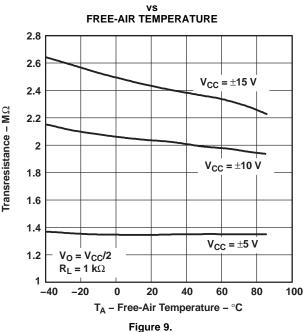
# COMMON-MODE REJECTION RATIO vs COMMON-MODE INPUT VOLTAGE



## COMMON-MODE REJECTION RATIO vs



## TRANSRESISTANCE



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#### TYPICAL CHARACTERISTICS (continued)

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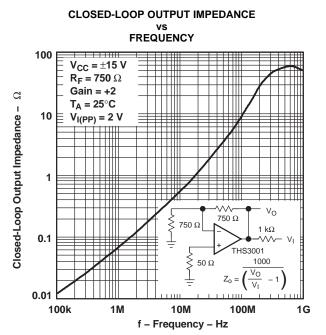


Figure 10.

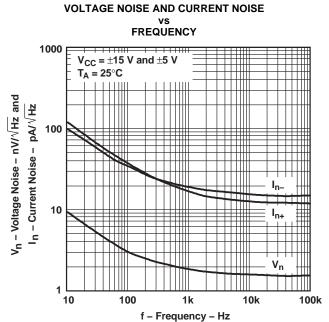
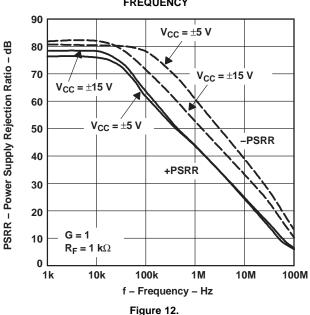


Figure 11.

## **POWER SUPPLY REJECTION RATIO** vs FREQUENCY



POWER SUPPLY REJECTION RATIO

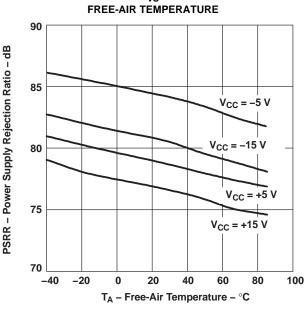


Figure 13.

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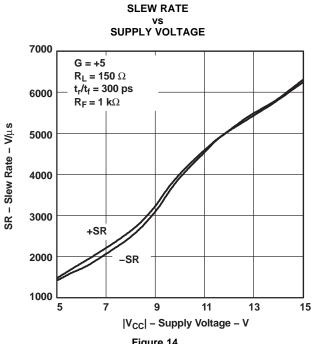


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#### **TYPICAL CHARACTERISTICS (continued)**



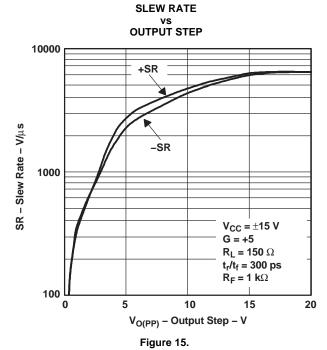
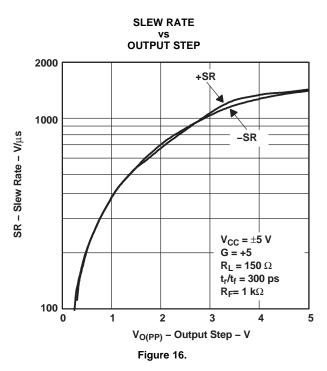


Figure 14.



**NORMALIZED SLEW RATE** 

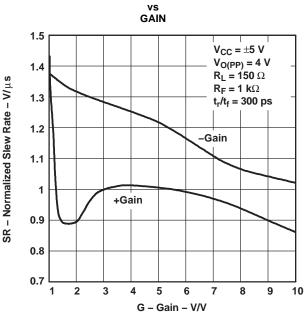


Figure 17.

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#### **TYPICAL CHARACTERISTICS (continued)**

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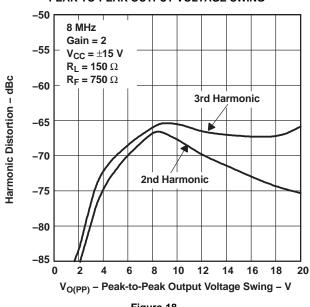


Figure 18.

## HARMONIC DISTORTION VS PEAK-TO-PEAK OUTPUT VOLTAGE SWING

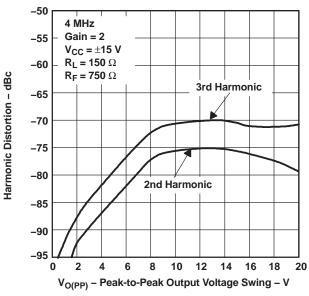
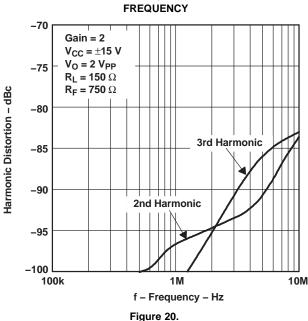


Figure 19.

# HARMONIC DISTORTION



HARMONIC DISTORTION

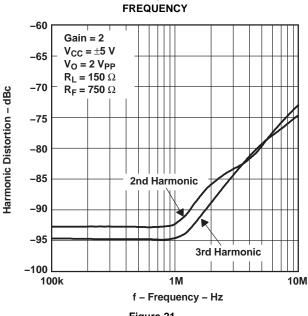


Figure 21.

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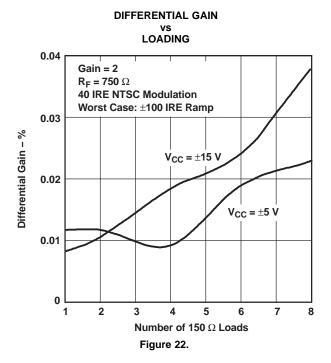
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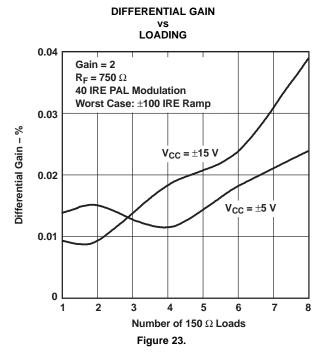


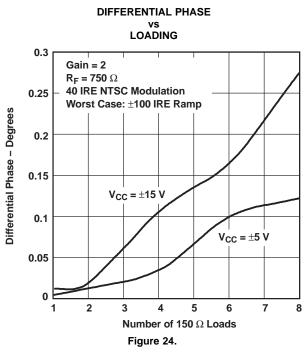
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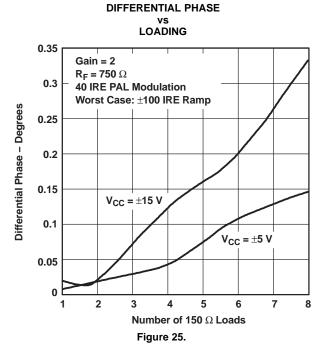
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#### **TYPICAL CHARACTERISTICS (continued)**









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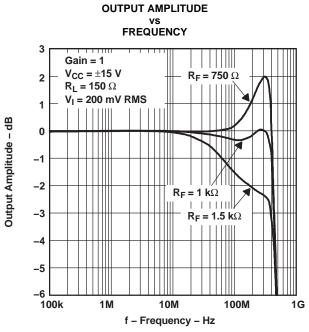
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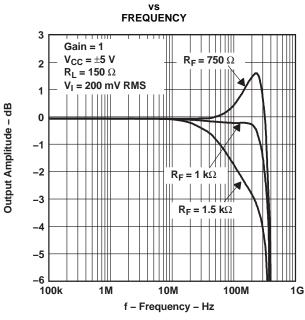
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#### **TYPICAL CHARACTERISTICS (continued)**



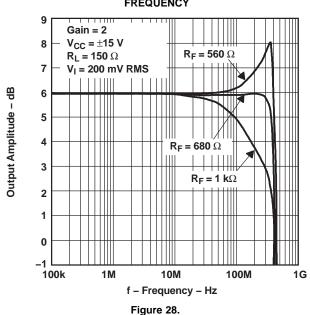




**OUTPUT AMPLITUDE** 

Figure 27.

# OUTPUT AMPLITUDE vs FREQUENCY



## OUTPUT AMPLITUDE vs FREQUENCY

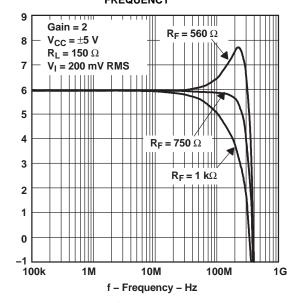


Figure 29.

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Output Amplitude - dB

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#### **TYPICAL CHARACTERISTICS (continued)**

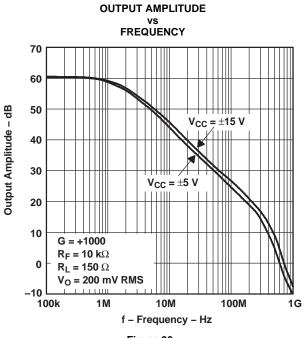
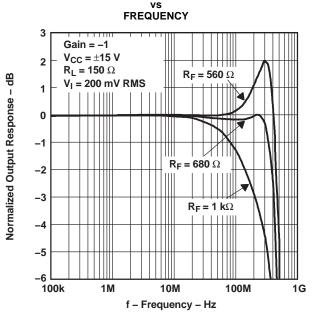


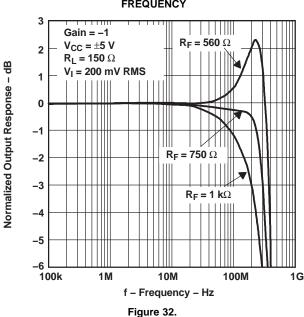
Figure 30.



NORMALIZED OUTPUT RESPONSE

Figure 31.

# NORMALIZED OUTPUT RESPONSE vs FREQUENCY



NORMALIZED OUTPUT RESPONSE
vs
FREQUENCY

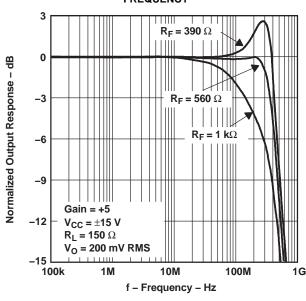


Figure 33.

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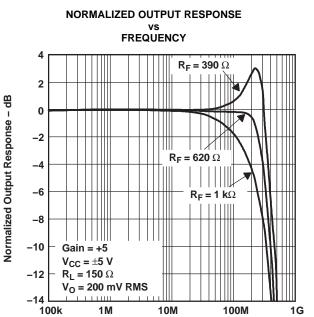


Figure 34.

f - Frequency - Hz

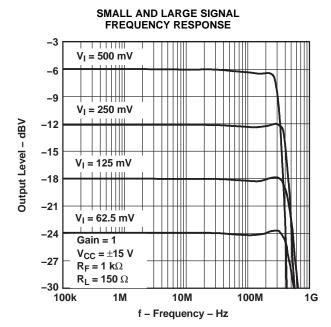


Figure 35.

## SMALL AND LARGE SIGNAL FREQUENCY RESPONSE

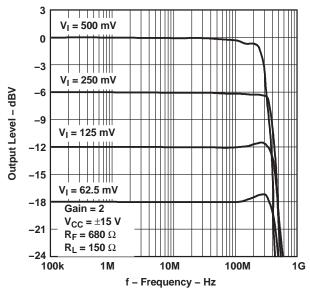


Figure 36.

#### **SMALL SIGNAL PULSE RESPONSE**

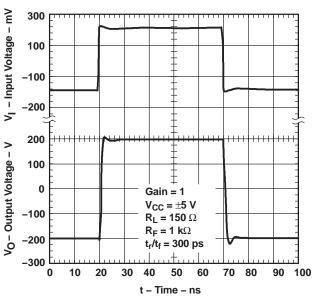


Figure 37.

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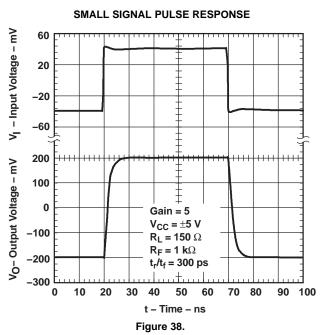


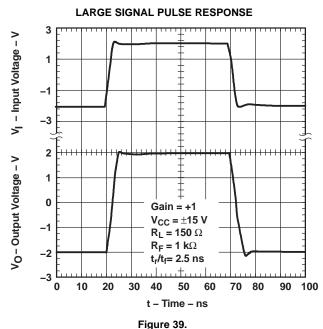
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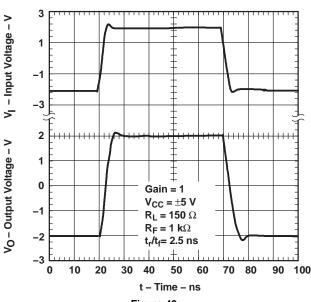
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#### **TYPICAL CHARACTERISTICS (continued)**









LARGE SIGNAL PULSE RESPONSE

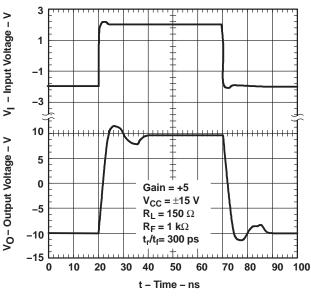


Figure 40.



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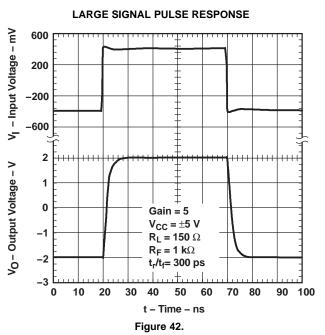
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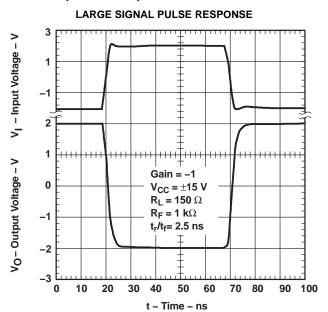
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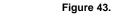
**INSTRUMENTS** 

#### **TYPICAL CHARACTERISTICS (continued)**

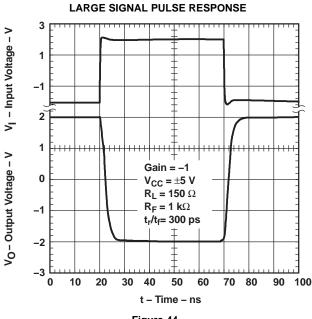
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LARGE SIGNAL PULSE RESPONSE



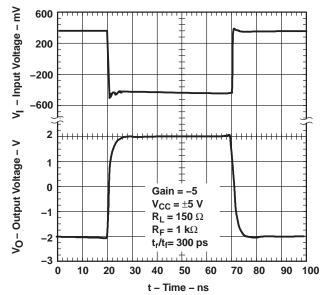


Figure 44.

Figure 45.

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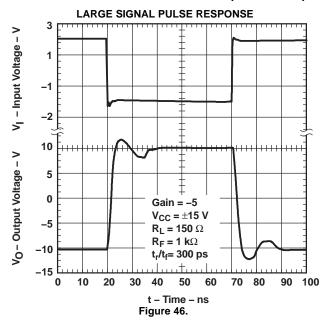


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#### **APPLICATION INFORMATION**

#### THEORY OF OPERATION

The THS3001 is a high-speed, operational amplifier configured in a current-feedback architecture. The device is built using a 30-V, dielectrically isolated, complementary bipolar process with NPN and PNP transistors possessing  $f_T$ s of several GHz. This configuration implements an exceptionally high-performance amplifier that has a wide bandwidth, high slew rate, fast settling time, and low distortion. A simplified schematic is shown in Figure 47.

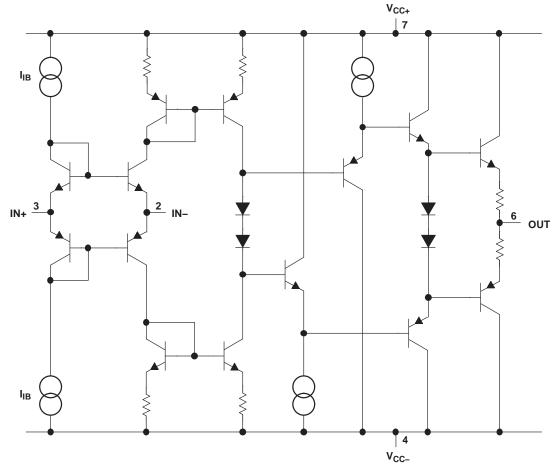


Figure 47. Simplified Schematic

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#### RECOMMENDED FEEDBACK AND GAIN RESISTOR VALUES

The THS3001 is fabricated using Texas Instruments 30-V complementary bipolar process, HVBiCOM. This process provides the excellent isolation and extremely high slew rates that result in superior distortion characteristics.

As with all current-feedback amplifiers, the bandwidth of the THS3001 is an inversely proportional function of the value of the feedback resistor (see Figures 26 to 34). The recommended resistors for the optimum frequency response are shown in Table 1. These should be used as a starting point and once optimum values are found, 1% tolerance resistors should be used to maintain frequency response characteristics. For most applications, a feedback resistor value of 1 k $\Omega$  is recommended - a good compromise between bandwidth and phase margin that yields a stable amplifier.

Consistent with current-feedback amplifiers, increasing the gain is best accomplished by changing the gain resistor, not the feedback resistor. This is because the bandwidth of the amplifier is dominated by the feedback resistor value and internal dominant-pole capacitor. The ability to control the amplifier gain independent of the bandwidth constitutes a major advantage of current-feedback amplifiers over conventional voltage-feedback amplifiers. Therefore, once a frequency response is found suitable to a particular application, adjust the value of the gain resistor to increase or decrease the overall amplifier gain.

Finally, it is important to realize the effects of the feedback resistance on distortion. Increasing the resistance decreases the loop gain and increases the distortion. It is also important to know that decreasing load impedance increases total harmonic distortion (THD). Typically, the third-order harmonic distortion increases more than the second-order harmonic distortion.

Table 1. Recommended Resistor Values for Optimum Frequency Response

GAIN	R <sub>F</sub> for V <sub>CC</sub> = ±15 V	R <sub>F</sub> for V <sub>CC</sub> = ±5 V							
1	1 kΩ	1 kΩ							
2, -1	680 Ω	750 Ω							
2	620 Ω	620 Ω							
5	560 Ω	620 Ω							

#### **OFFSET VOLTAGE**

The output offset voltage,  $(V_{OO})$  is the sum of the input offset voltage  $(V_{IO})$  and both input bias currents  $(I_{IB})$  times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

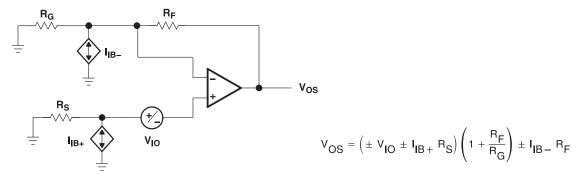


Figure 48. Output Offset Voltage Model

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#### NOISE CALCULATIONS

Noise can cause errors on small signals. This is especially true for amplifying small signals coming over a transmission line or an antenna. The noise model for current-feedback amplifiers (CFB) is the same as for voltage feedback amplifiers (VFB). The only difference between the two is that CFB amplifiers generally specify different current-noise parameters for each input, while VFB amplifiers usually only specify one noise-current parameter. The noise model is shown in Figure 49. This model includes all of the noise sources as follows:

- $e_n = Amplifier internal voltage noise (nV/<math>\sqrt{Hz}$ )
- IN+ = Nonverting current noise (pA/√Hz)
- IN- = Inverting current noise (pA/√Hz)
- e<sub>Rx</sub> = Thermal voltage noise associated with each resistor (e<sub>Rx</sub> = 4 kTR<sub>x</sub>)

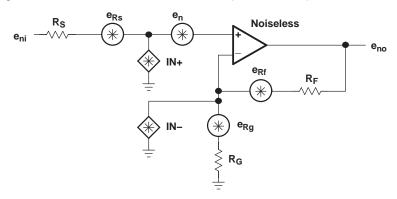


Figure 49. Noise Model

The total equivalent input noise density (eni) is calculated by using the following equation:

$$\mathbf{e}_{\text{ni}} = \sqrt{\left(\mathbf{e}_{\text{n}}\right)^2 + \left(\mathsf{IN} + \times \mathsf{R}_{\text{S}}\right)^2 + \left(\mathsf{IN} - \times \left(\mathsf{R}_{\text{F}} \parallel \mathsf{R}_{\text{G}}\right)\right)^2 + 4 \, \mathsf{kTR}_{\text{S}} + 4 \, \mathsf{kT} \left(\mathsf{R}_{\text{F}} \parallel \mathsf{R}_{\text{G}}\right)}}$$

Where:

 $k = Boltzmann's constant = 1.380658 \times 10^{-23}$ 

T = Temperature in degrees Kelvin (273 +°C)

 $R_F \parallel R_G$  = Parallel resistance of  $R_F$  and  $R_G$ 

To get the equivalent output noise of the amplifier, just multiply the equivalent input noise density ( $e_{ni}$ ) by the overall amplifier gain ( $A_V$ ).

$$e_{no} = e_{ni} A_V = e_{ni} \left( 1 + \frac{R_F}{R_G} \right)$$
 (Noninverting Case)

As the previous equations show, to keep noise at a minimum, small value resistors should be used. As the closed-loop gain is increased (by reducing  $R_{\rm G}$ ), the input noise is reduced considerably because of the parallel resistance term. This leads to the general conclusion that the most dominant noise sources are the source resistor ( $R_{\rm S}$ ) and the internal amplifier noise voltage ( $e_{\rm n}$ ). Because noise is summed in a root-mean-squares method, noise sources smaller than 25% of the largest noise source can be effectively ignored. This can greatly simplify the formula and make noise calculations much easier.

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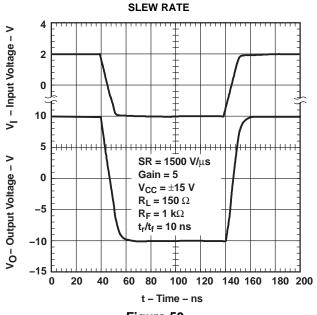
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#### **SLEW RATE**

The slew rate performance of a current-feedback amplifier, like the THS3001, is affected by many different factors. Some of these factors are external to the device, such as amplifier configuration and PCB parasitics, and others are internal to the device, such as available currents and node capacitance. Understanding some of these factors should help the PCB designer arrive at a more optimum circuit with fewer problems.

Whether the THS3001 is used in an inverting amplifier configuration or a noninverting configuration can impact the output slew rate. As can be seen from the specification tables as well as some of the figures in this data sheet, slew-rate performance in the inverting configuration is faster than in the noninverting configuration. This is because in the inverting configuration the input terminals of the amplifier are at a virtual ground and do not significantly change voltage as the input changes. Consequently, the time to charge any capacitance on these input nodes is less than for the noninverting configuration, where the input nodes actually do change in voltage an amount equal to the size of the input step. In addition, any PCB parasitic capacitance on the input nodes degrades the slew rate further simply because there is more capacitance to charge. Also, if the supply voltage  $(V_{CC})$  to the amplifier is reduced, slew rate decreases because there is less current available within the amplifier to charge the capacitance on the input nodes as well as other internal nodes.

Internally, the THS3001 has other factors that impact the slew rate. The amplifier's behavior during the slew-rate transition varies slightly depending upon the rise time of the input. This is because of the way the input stage handles faster and faster input edges. Slew rates (as measured at the amplifier output) of less than about 1500 V/µs are processed by the input stage in a linear fashion. Consequently, the output waveform smoothly transitions between initial and final voltage levels. This is shown in Figure 50. For slew rates greater than 1500 V/µs, additional slew-enhancing transistors present in the input stage begin to turn on to support these faster signals. The result is an amplifier with extremely fast slew-rate capabilities. Figure 50 and Figure 51 show waveforms for these faster slew rates. The additional aberrations present in the output waveform with these faster-slewing input signals are due to the brief saturation of the internal current mirrors. This phenomenon, which typically lasts less than 20 ns, is considered normal operation and is not detrimental to the device in any way. If for any reason this type of response is not desired, then increasing the feedback resistor or slowing down the input-signal slew rate reduces the effect.



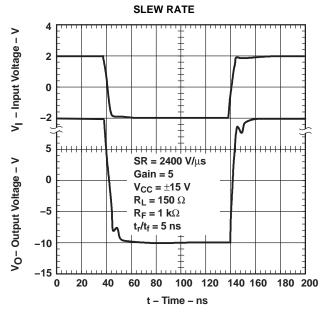


Figure 50.

Figure 51.

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#### DRIVING A CAPACITIVE LOAD

Driving capacitive loads with high-performance amplifiers is not a problem as long as certain precautions are taken. The first is to realize that the THS3001 has been internally compensated to maximize its bandwidth and slew-rate performance. When the amplifier is compensated in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high-frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series with the output of the amplifier, as shown in Figure 52. A minimum value of  $20\Omega$  should work well for most applications. For example, in 75- $\Omega$  transmission systems, setting the series resistor value to 75  $\Omega$  both isolates any capacitance loading and provides the proper line impedance matching at the source end.

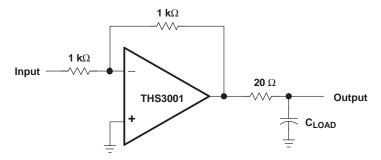


Figure 52. Driving a Capacitive Load

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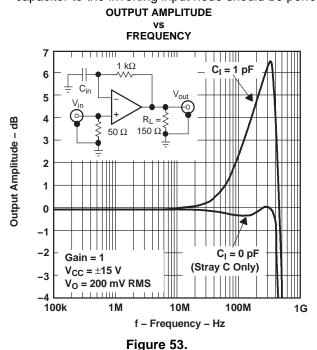
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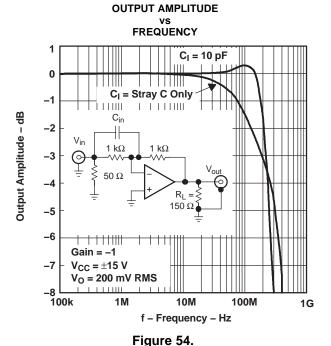
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#### PCB DESIGN CONSIDERATIONS

Proper PCB design techniques in two areas are important to ensure proper operation of the THS3001. These areas are high-speed layout techniques and thermal-management techniques. Because the THS3001 is a high-speed part, the following guidelines are recommended.

- Ground plane It is essential that a ground plane be used on the board to provide all components with a low
  inductive ground connection, but should be removed from below the output and negative input pins as noted
  below.
- The DGN package option includes a thermal pad for increased thermal performance. When using this package, it is recommended to distribute the negative supply as a power plane, and tie the thermal pad to this supply with multiple vias for proper power dissipation. It is not recommended to tie the thermal pad to ground when using split supply (±V) as this will cause worse distortion performance than shown in this data sheet.
- Input stray capacitance To minimize potential problems with amplifier oscillation, the capacitance at the inverting input of the amplifiers must be kept to a minimum. To do this, PCB trace runs to the inverting input must be as short as possible, the ground plane must be removed under any etch runs connected to the inverting input, and external components should be placed as close as possible to the inverting input. This is especially true in the noninverting configuration. An example of this can be seen in Figure 53, which shows what happens when a 1-pF capacitor is added to the inverting input terminal. The bandwidth increases at the expense of peaking. This is because some of the error current is flowing through the stray capacitor instead of the inverting node of the amplifier. Although, while the device is in the inverting mode, stray capacitance at the inverting input has a minimal effect. This is because the inverting node is at a virtual ground and the voltage does not fluctuate nearly as much as in the noninverting configuration. This can be seen in Figure 54, where a 10-pF capacitor adds only 0.35 dB of peaking. In general, as the gain of the system increases, the output peaking due to this capacitor decreases. While this can initially look like a faster and better system, overshoot and ringing are more likely to occur under fast transient conditions. So proper analysis of adding a capacitor to the inverting input node should be performed for stable operation.





• Proper power-supply decoupling - Use a minimum 6.8-µF tantalum capacitor in parallel with a 0.1-µF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1-µF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1-µF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting etch makes the capacitor less effective. The designer should strive for distances of less than 0.1 inch between the device power terminal and the ceramic capacitors.

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#### THERMAL INFORMATION

The THS3001 incorporates output-current-limiting protection. Should the output become shorted to ground, the output current is automatically limited to the value given in the data sheet. While this protects the output against excessive current, the device internal power dissipation increases due to the high current and large voltage drop across the output transistors. Continuous output shorts are not recommended and could damage the device. Additionally, connection of the amplifier output to one of the supply rails ( $\pm V_{CC}$ ) is not recommended. Failure of the device is possible under this condition and should be avoided. But, the THS3001 does not incorporate thermal-shutdown protection. Because of this, special attention must be paid to the device's power dissipation or failure may result.

The thermal coefficient  $\theta_{JA}$  is approximately 169°C/W for the SOIC 8-pin D package. For a given  $\theta_{JA}$ , the maximum power dissipation, shown in Figure 55, is calculated by the following formula:

$$P_{D} = \left(\frac{T_{MAX}^{-T}A}{\theta_{JA}}\right)$$

Where:

P<sub>D</sub> = Maximum power dissipation of THS3001 (watts)

 $T_{MAX}$  = Absolute maximum junction temperature (150°C)

 $T_A$  = Free-ambient air temperature (°C)

θ<sub>JA</sub> = Thermal coefficient from die junction to ambient air (°C/W)

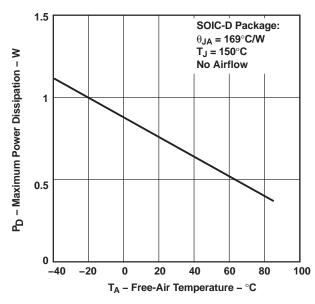


Figure 55. Maximum Power Dissipation vs Free-Air Temperature

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#### **GENERAL CONFIGURATIONS**

A common error for the first-time CFB user is the creation of a unity gain buffer amplifier by shorting the output directly to the inverting input. A CFB amplifier in this configuration will oscillate and is *not* recommended. The THS3001, like all CFB amplifiers, *must* have a feedback resistor for stable operation. Additionally, placing capacitors directly from the output to the inverting input is not recommended. This is because, at high frequencies, a capacitor has a low impedance. This results in an unstable amplifier and should not be considered when using a current-feedback amplifier. Because of this, integrators and simple low-pass filters, which are easily implemented on a VFB amplifier, have to be designed slightly differently. If filtering is required, simply place an RC-filter at the noninverting terminal of the operational-amplifier (see Figure 56).

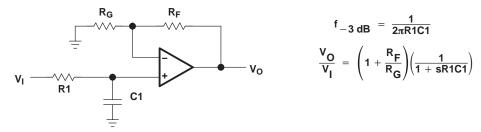


Figure 56. Single-Pole Low-Pass Filter

If a multiple-pole filter is required, the use of a Sallen-Key filter can work well with CFB amplifiers. This is because the filtering elements are not in the negative feedback loop and stability is not compromised. Because of their high slew rates and high bandwidths, CFB amplifiers can create accurate signals and help minimize distortion. An example is shown in Figure 57.

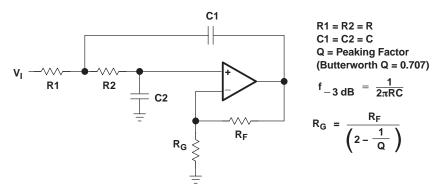


Figure 57. 2-Pole Low-Pass Sallen-Key Filter

There are two simple ways to create an integrator with a CFB amplifier. The first, shown in Figure 58, adds a resistor in series with the capacitor. This is acceptable because at high frequencies, the resistor is dominant and the feedback impedance never drops below the resistor value. The second, shown in Figure 59, uses positive feedback to create the integration. Caution is advised because oscillations can occur due to the positive feedback.

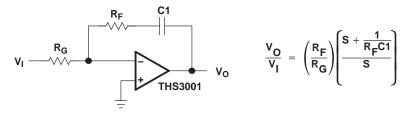


Figure 58. Inverting CFB Integrator

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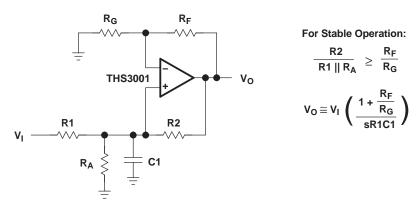


Figure 59. Noninverting CFB Integrator

The THS3001 may also be employed as a good video distribution amplifier. One characteristic of distribution amplifiers is the fact that the differential phase (DP) and the differential gain (DG) are compromised as the number of lines increases and the closed-loop gain increases (see Figures 22 to 25 for more information). Be sure to use termination resistors throughout the distribution system to minimize reflections and capacitive loading.

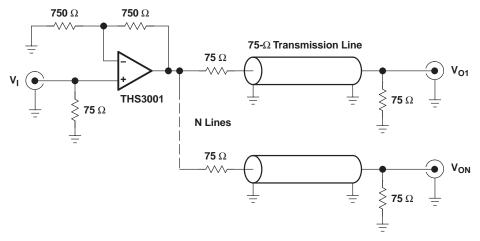


Figure 60. Video Distribution Amplifier Application

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THS3001

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#### **EVALUATION BOARD**

An evaluation board is available for the THS3001 (THS3001EVM). The board has been configured for low parasitic capacitance in order to realize the full performance of the amplifier. A schematic of the evaluation board is shown in Figure 61. The circuitry has been designed so that the amplifier may be used in either an inverting or noninverting configuration. For more detailed information, refer to the *THS3001 EVM User's Guide* (literature number SLOU021). The evaluation board can be ordered online through the TI web site, or through your local TI sales office or distributor.

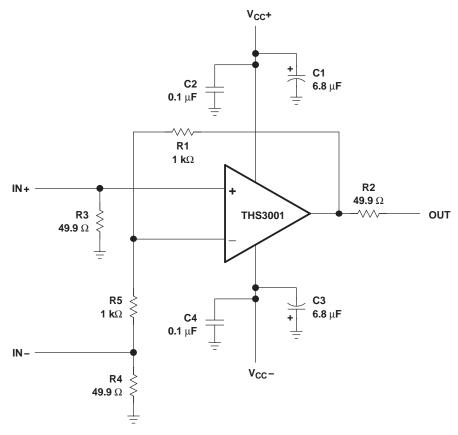


Figure 61. THS3001 Evaluation Board Schematic

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## THS3001



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#### **REVISION HISTORY**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

C	hanges from Revision G (March, 2008) to Revision H	Page
•	Updated document format to current standards	1
•	Deleted references to HV version in SOIC package; this version is not available	2
•	Updated information about THS3001EVM availability	27

Product Folder Link(s): THS3001

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PACKAGE OPTION ADDENDUM

10-Jun-2014

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
THS3001CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	3001C	Sample
THS3001CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	3001C	Sample
THS3001CDGN	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	ADP	Sample
THS3001CDGNG4	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	ADP	Sample
THS3001CDGNR	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	ADP	Sample
THS3001CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	3001C	Sampl
THS3001CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	3001C	Sampl
THS3001HVCDGN	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	BNK	Sampl
THS3001HVIDGN	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	BNJ	Samp
THS3001HVIDGNG4	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BNJ	Samp
THS3001ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		30011	Samp
THS3001IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		30011	Sampl
THS3001IDGN	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM		ADQ	Samp
THS3001IDGNG4	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		ADQ	Samp
THS3001IDGNR	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM		ADQ	Samp
THS3001IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		30011	Samp

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

Addendum-Page 1



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PACKAGE OPTION ADDENDUM

10-Jun-2014

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Ti's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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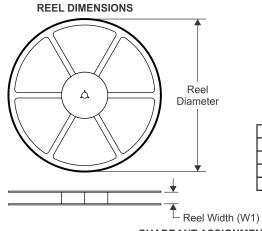
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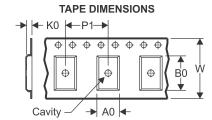


## **PACKAGE MATERIALS INFORMATION**

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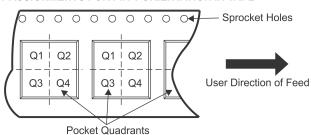
#### TAPE AND REEL INFORMATION





	A0	Dimension designed to accommodate the component width
- 1	DΛ	Dimension designed to accommodate the component length

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE** 



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS3001CDGNR	MSOP- Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS3001CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS3001IDGNR	MSOP- Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS3001IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

Dimension designed to accommodate the component thickness

W Overall width of the carrier tape

P1 Pitch between successive cavity centers

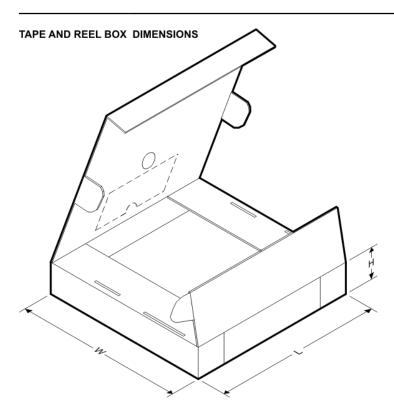
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## **PACKAGE MATERIALS INFORMATION**

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS3001CDGNR	MSOP-PowerPAD	DGN	8	2500	364.0	364.0	27.0
THS3001CDR	SOIC	D	8	2500	367.0	367.0	38.0
THS3001IDGNR	MSOP-PowerPAD	DGN	8	2500	364.0	364.0	27.0
THS3001IDR	SOIC	D	8	2500	367.0	367.0	38.0

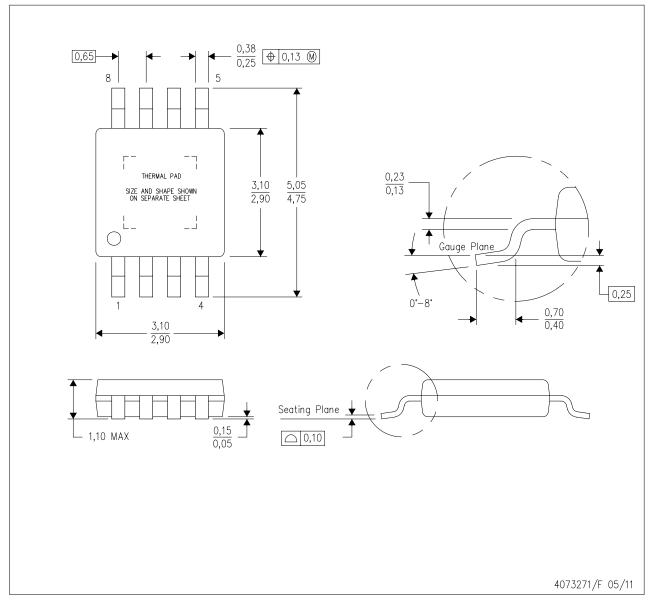
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**MECHANICAL DATA** 

DGN (S-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <a href="https://www.ti.com">http://www.ti.com</a>>.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions. F. Falls within JEDEC MO-187 variation AA-T

PowerPAD is a trademark of Texas Instruments.



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## THERMAL PAD MECHANICAL DATA

DGN (S-PDSO-G8)

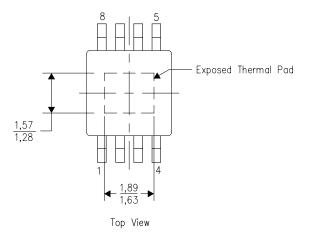
PowerPAD™ PLASTIC SMALL OUTLINE

#### THERMAL INFORMATION

This PowerPAD package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

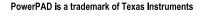
The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

4206323-2/1 12/11

NOTE: All linear dimensions are in millimeters







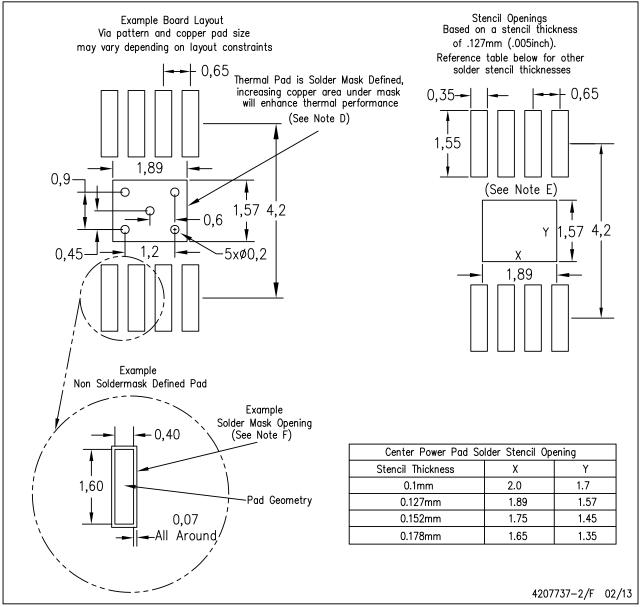
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#### LAND PATTERN DATA

DGN (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
- Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PowerPAD is a trademark of Texas Instruments

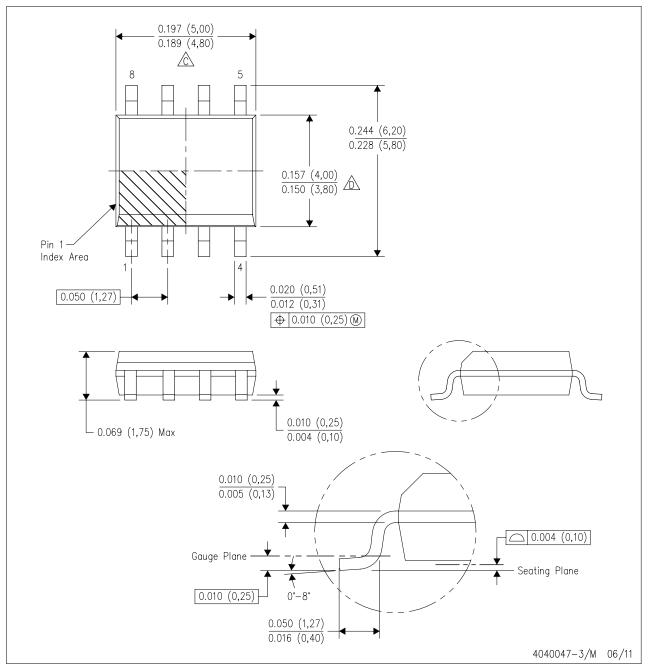




#### **MECHANICAL DATA**

## D (R-PDSO-G8)

#### PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



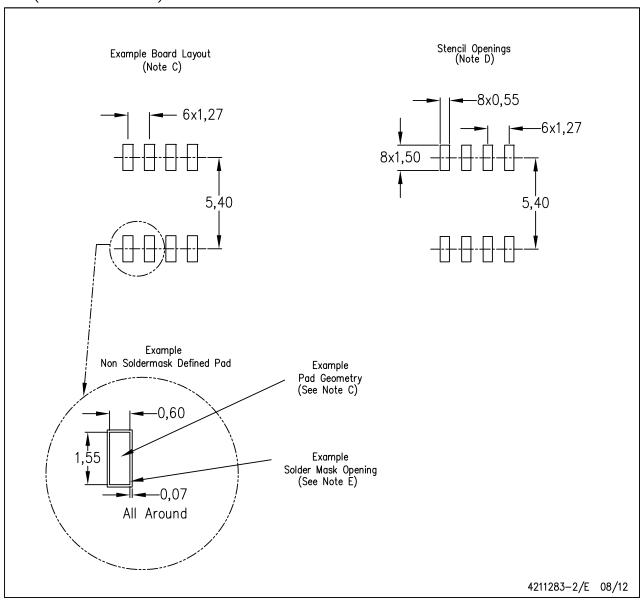




#### LAND PATTERN DATA

## D (R-PDSO-G8)

#### PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





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